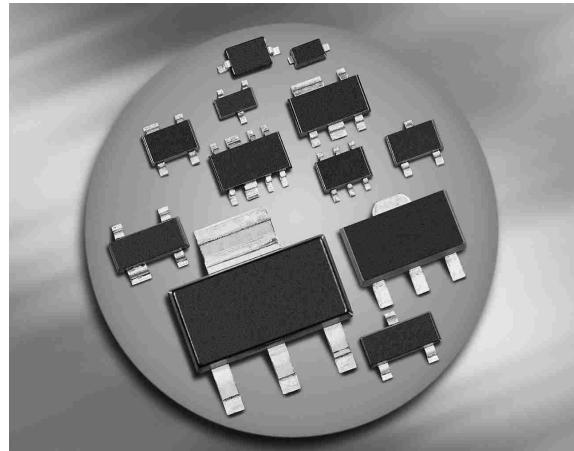
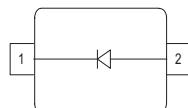


Silicon Variable Capacitance Diodes

- For tuning of extended frequency band in VHF TV / VTR tuners
- High capacitance ratio
- Low series inductance
- Low series resistance
- Excellent uniformity and matching due to "in-line" matching assembly procedure
- Pb-free (RoHS compliant) package



BB639
BB659



Type	Package	Configuration	L_S (nH)	Marking
BB639	SOD323	single	1.8	yellow S
BB659	SCD80	single	0.6	DE

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	30	V
Peak reverse voltage ($R \geq 5\text{k}\Omega$)	V_{RM}	35	
Forward current	I_F	20	mA
Operating temperature range	T_{op}	-55 ... 150	°C
Storage temperature	T_{stg}	-55 ... 150	

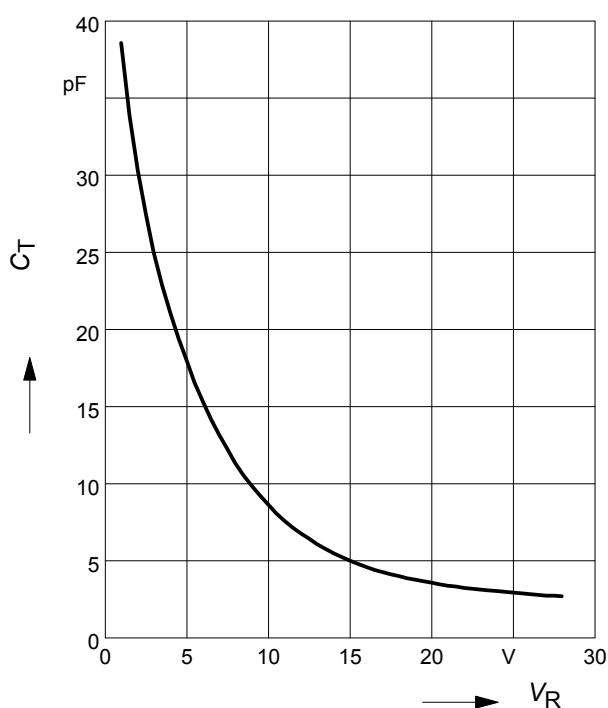
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Reverse current $V_R = 30 \text{ V}$	I_R	-	-	10	nA
$V_R = 30 \text{ V}, T_A = 85^\circ\text{C}$		-	-	200	
AC Characteristics					
Diode capacitance $V_R = 1 \text{ V}, f = 1 \text{ MHz}$	C_T	36	38.3	40	pF
$V_R = 2 \text{ V}, f = 1 \text{ MHz}$		27.7	29.75	31.8	
$V_R = 25 \text{ V}, f = 1 \text{ MHz}$		2.5	2.85	3.2	
$V_R = 28 \text{ V}, f = 1 \text{ MHz}$		2.4	2.6	2.9	
Capacitance ratio $V_R = 1 \text{ V}, V_R = 28 \text{ V}, f = 1 \text{ MHz}$	C_{T1}/C_{T28}	13.5	14.7	-	
Capacitance ratio $V_R = 2 \text{ V}, V_R = 25 \text{ V}, f = 1 \text{ MHz}$	C_{T2}/C_{T25}	9.8	10.4	-	
Capacitance matching ¹⁾ $V_R = 1 \text{ V}, V_R = 28 \text{ V}, f = 1 \text{ MHz}, 7 \text{ diode sequence}$ BB639	$\Delta C_T/C_T$	-	-	2.5	%
$V_R = 1 \text{ V}, V_R = 28 \text{ V}, f = 1 \text{ MHz}, 4 \text{ diode sequence}$ BB659		-	0.3	1	
$V_R = 1 \text{ V}, V_R = 28 \text{ V}, f = 1 \text{ MHz}, 7 \text{ diode sequence}$ BB659		-	0.4	2	
Series resistance $V_R = 5 \text{ V}, f = 470 \text{ MHz}$	r_S	-	0.65	0.7	Ω

¹⁾For details please refer to Application Note 047.

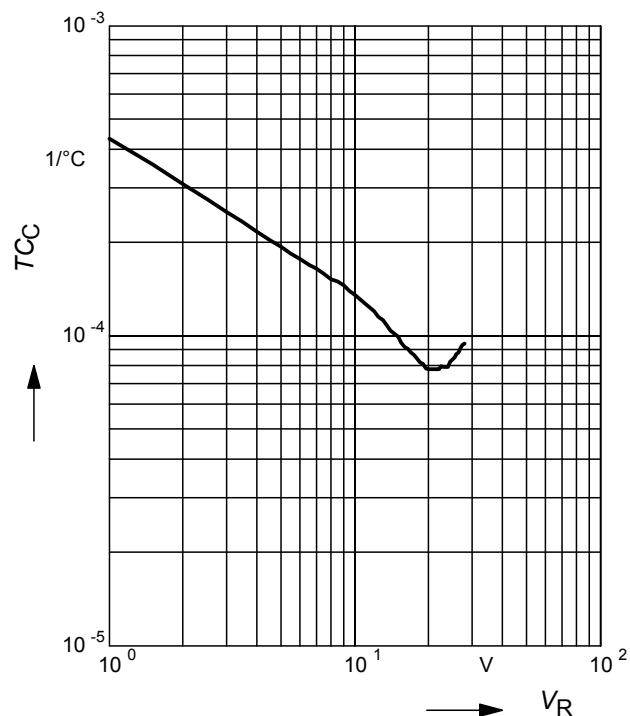
Diode capacitance $C_T = f(V_R)$

$f = 1\text{MHz}$



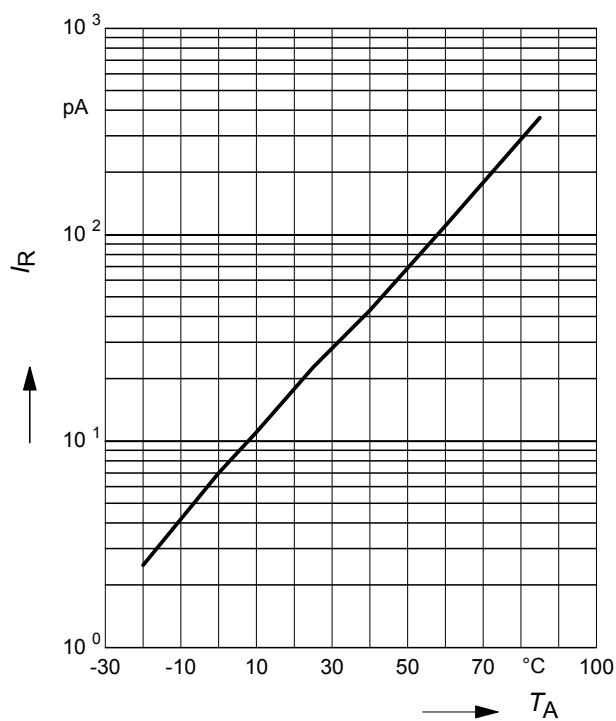
Temperature coefficient of the diode capacitance $T_{Cc} = f(V_R)$

$T_A = \text{Parameter}$



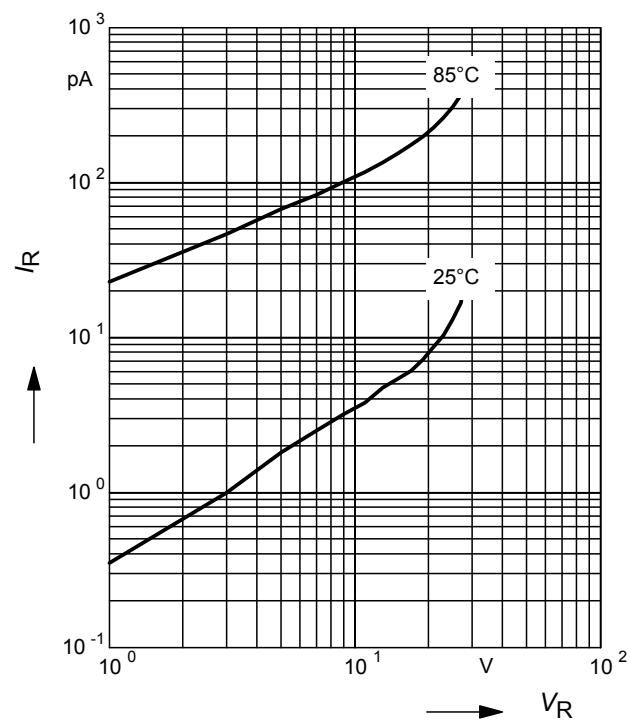
Reverse current $I_R = f(T_A)$

$V_R = 28\text{V}$

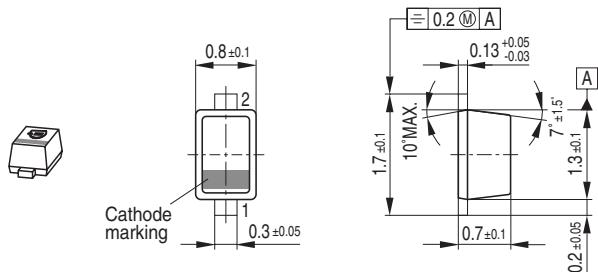


Reverse current $I_R = f(V_R)$

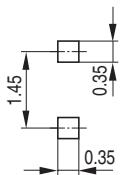
$T_A = \text{Parameter}$



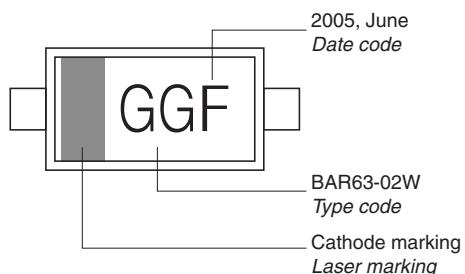
Package Outline



Foot Print

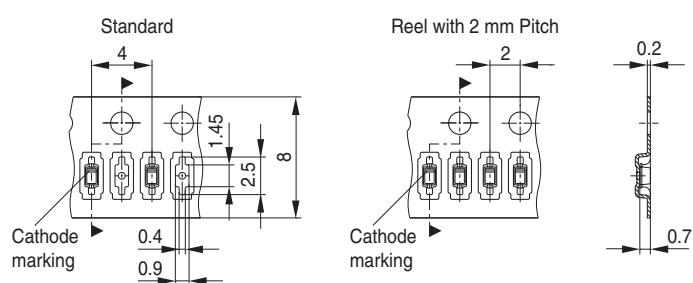


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
 Reel ø180 mm = 8.000 Pieces/Reel (2 mm Pitch)
 Reel ø330 mm = 10.000 Pieces/Reel

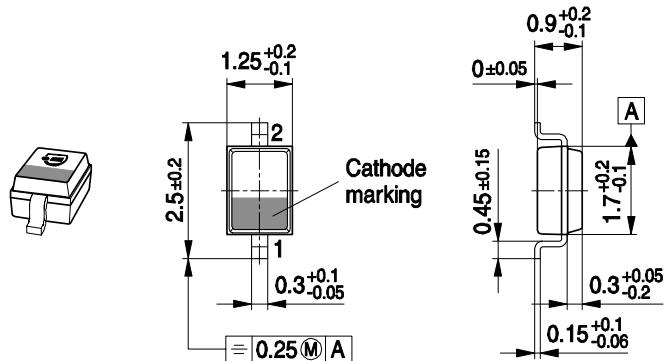


**Date Code marking for discrete packages with
one digit (SCD80, SC79, SC75¹⁾) CES-Code**

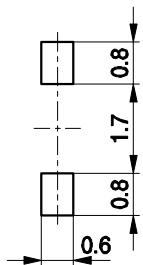
Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	a	p	A	P	a	p	A	P	a	p	A	P
02	b	q	B	Q	b	q	B	Q	b	q	B	Q
03	c	r	C	R	c	r	C	R	c	r	C	R
04	d	s	D	S	d	s	D	S	d	s	D	S
05	e	t	E	T	e	t	E	T	e	t	E	T
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	v	G	V	g	v	G	V	g	v	G	V
08	h	x	H	X	h	x	H	X	h	x	H	X
09	j	y	J	Y	j	y	J	Y	j	y	J	Y
10	k	z	K	Z	k	z	K	Z	k	z	K	Z
11	l	2	L	4	l	2	L	4	l	2	L	4
12	n	3	N	5	n	3	N	5	n	3	N	5

1) New Marking Layout for SC75, implemented at October 2005.

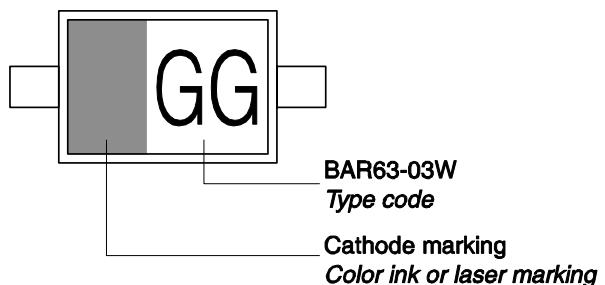
Package Outline



Foot Print



Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
 Reel ø330 mm = 10.000 Pieces/Reel

